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## 1. General description

NPN/NPN matched double transistors in a small SOT457 (SC-74) Surface-Mounted Device (SMD) plastic package.

PNP/PNP complement: BCM53DS

### 2. Features and benefits

- High collector current capability I<sub>C</sub> and I<sub>CM</sub>
- Reduces component count
- Reduces pick and place costs
- Current gain matching 5%
- · Application-optimized pinout
- AEC-Q101 qualified

## 3. Applications

- Current mirror
- Differential amplifier
- · Linear voltage regulators
- MOSFET drivers
- · High-side switches
- Power management
- Amplifiers

## 4. Quick reference data

#### Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
Per transistor	Per transistor							
V <sub>CEO</sub>	collector-emitter voltage	open base		-	-	80	V	
I <sub>C</sub>	collector current			-	-	1	Α	
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms		-	-	2	Α	
h <sub>FE</sub>	DC current gain	$V_{CE}$ = 2 V; $I_{C}$ = 150 mA; $T_{amb}$ = 25 °C	[1]	63	-	250		
Per device								
h <sub>FE1</sub> /h <sub>FE2</sub>	DC current gain matching	$V_{CE} = 5 \text{ V}; I_{C} = 2 \text{ mA}; T_{amb} = 25 \text{ °C}$		0.95	1	1.05		



### 80 V, 1 A NPN/NPN matched double transistors

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>BE1</sub> -V <sub>BE2</sub>	base-emitter voltage matching		[2]	-	-	2	mV

- [1] Pulse test:  $t_0 \le 300 \,\mu\text{s}$ ;  $\delta \le 0.02$
- [2] The smaller of the two values is subtracted from the larger value.

# 5. Pinning information

### **Table 2. Pinning information**

Pin	Symbol	Description	Simplified outline	Graphic symbol	
1	B1	base TR1	<u> </u>	C1 E1 E2	
2	B2	base TR2		TR1 TR2	
3	C2	collector TR2	0 1 1 2 3		
4	E2	emitter TR2	TSOP6 (SOT457)		_
5	E1	emitter TR1			aaa-024629
6	C1	collector TR1			

# 6. Ordering information

#### **Table 3. Ordering information**

Type number	Package					
	Name	Description	Version			
BCM56DS	TSOP6	plastic, surface-mounted package (SC-74)	SOT457			

## 7. Marking

#### Table 4. Marking codes

Type number	Marking code
BCM56DS	3D

80 V, 1 A NPN/NPN matched double transistors

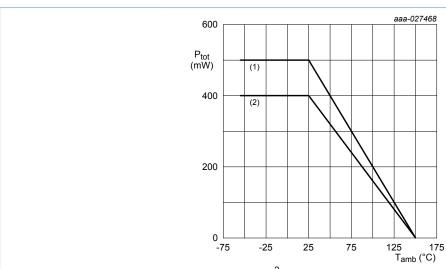
# 8. Limiting values

### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC60134).

Symbol	Parameter	Conditions		Min	Max	Unit
Per transist	or		'			_
V <sub>CBO</sub>	collector-base voltage	open emitter		-	100	V
$V_{CEO}$	collector-emitter voltage	open base		-	80	V
V <sub>EBO</sub>	emitter-base voltage	open collector		-	5	V
I <sub>C</sub>	collector current			-	1	Α
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms		-	2	Α
I <sub>Blim</sub>	limiting base current			-	0.2	Α
I <sub>BM</sub>	peak base current	single pulse; t <sub>p</sub> ≤ 1 ms		-	0.3	Α
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	270	mW
			[2]	-	320	mW
Per device						
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	400	mW
			[2]	-	500	mW
Tj	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C

- Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint. Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated; mounting pad for collector 1 cm<sup>2</sup>.



- (1) = FR4 PCB, single sided copper, 1 cm<sup>2</sup>
- (2) = FR4 PCB, single sided copper, standard footprint

Per device: Power derating curves Fig. 1.

#### 80 V, 1 A NPN/NPN matched double transistors

### 9. Thermal characteristics

**Table 6. Thermal characteristics** 

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transist	tor				,	,	
R <sub>th(j-a)</sub>	thermal resistance	in free air	[1]	-	-	463	K/W
	from junction to ambient  thermal resistance		[2]	-	-	391	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point			-	-	150	K/W
Per device							
$R_{\text{th(j-a)}}$	thermal resistance	in free air	[1]	-	-	313	K/W
	from junction to ambient		[2]	-	-	250	K/W

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated; mounting pad for collector 1 cm<sup>2</sup>.

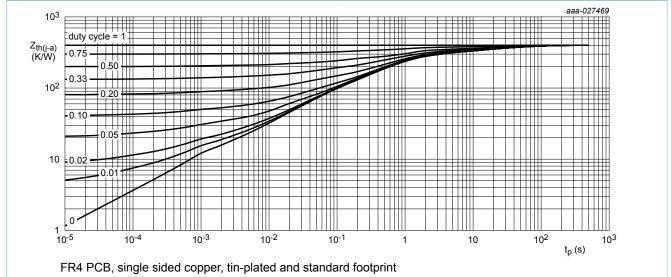
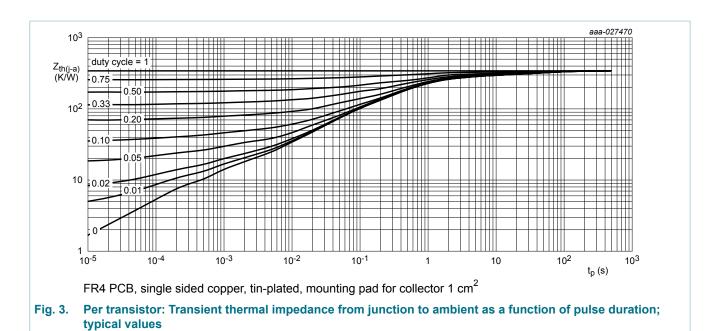


Fig. 2. Per transistor: Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

### 80 V, 1 A NPN/NPN matched double transistors



### 80 V, 1 A NPN/NPN matched double transistors

## 10. Characteristics

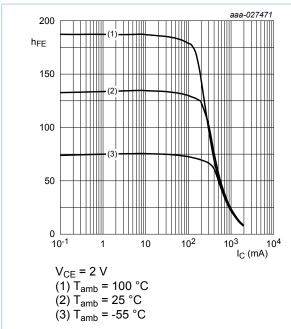
#### Table 7. Characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transisto	or						,
V <sub>(BR)CBO</sub>	collector-base breakdown voltage	I <sub>C</sub> = 100 μA; I <sub>E</sub> = 0 A		100	-	-	V
V <sub>(BR)CEO</sub>	collector-emitter breakdown voltage	$I_C = 2 \text{ mA}; I_B = 0 \text{ A}$		80	-	-	V
$V_{(BR)EBO}$	emitter-base breakdown voltage	$I_C = 0 \text{ A}; I_E = 100 \mu\text{A}$		5	-	-	V
I <sub>CBO</sub>	collector-base cut-off	V <sub>CB</sub> = 30 V; I <sub>E</sub> = 0 A; T <sub>amb</sub> = 25 °C		-	-	100	nA
	current	V <sub>CB</sub> = 30 V; I <sub>E</sub> = 0 A; T <sub>j</sub> = 150 °C		-	-	10	μΑ
I <sub>EBO</sub>	emitter-base cut-off current	V <sub>EB</sub> = 5 V; I <sub>C</sub> = 0 A; T <sub>amb</sub> = 25 °C		-	-	100	nA
h <sub>FE</sub>	DC current gain	$V_{CE}$ = 5 V; $I_{C}$ = 2 mA; $T_{amb}$ = 25 °C		63	-	-	
		V <sub>CE</sub> = 2 V; I <sub>C</sub> = 150 mA; T <sub>amb</sub> = 25 °C	[1]	63	-	250	
		$V_{CE}$ = 2 V; $I_{C}$ = 500 mA; $T_{amb}$ = 25 °C	[1]	40	-	-	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_C$ = 500 mA; $I_B$ = 50 mA; $T_{amb}$ = 25 °C	[1]	-	-	500	mV
$V_{BE}$	base-emitter voltage	$V_{CE}$ = 2 V; $I_{C}$ = 500 mA; $T_{amb}$ = 25 °C	[1]	-	-	1	V
C <sub>c</sub>	collector capacitance	$V_{CB}$ = 10 V; $I_{E}$ = 0 A; $i_{e}$ = 0 A; $f$ = 1 MHz; $T_{amb}$ = 25 °C		-	4.5	-	pF
f <sub>T</sub>	transition frequency	$V_{CE}$ = 5 V; $I_{C}$ = 50 mA; f = 100 MHz; $T_{amb}$ = 25 °C		100	155	-	MHz
Per device							
h <sub>FE1</sub> /h <sub>FE2</sub>	DC current gain matching	$V_{CE} = 5 \text{ V}; I_{C} = 2 \text{ mA}; T_{amb} = 25 \text{ °C}$		0.95	1	1.05	
V <sub>BE1</sub> -V <sub>BE2</sub>	base-emitter voltage matching		[2]	-	-	2	mV

Pulse test:  $t_p \le 300~\mu s;~\delta \le 0.02$  The smaller of the two values is subtracted from the larger value.

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#### 80 V, 1 A NPN/NPN matched double transistors



DC current gain as a function of collector Fig. 4. current; typical values

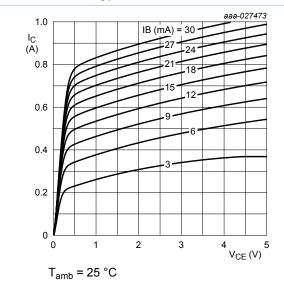
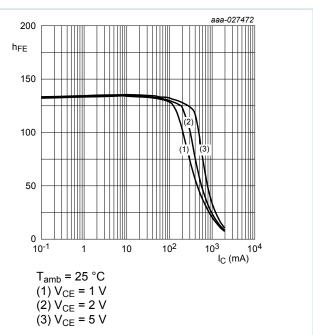
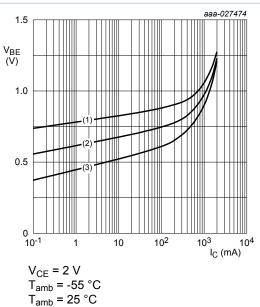


Fig. 6. Collector current as a function of collectoremitter voltage; typical values



DC current gain as a function of collector Fig. 5. current; typical values



 $T_{amb} = 25 \,^{\circ}C$   $T_{amb} = 100 \,^{\circ}C$ 

Fig. 7. Base-emitter voltage as a function of collector current; typical values

#### 80 V, 1 A NPN/NPN matched double transistors

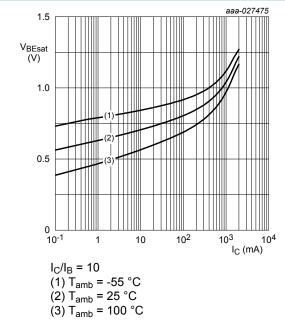


Fig. 8. Base-emitter saturation voltage as a function of collector current; typical values

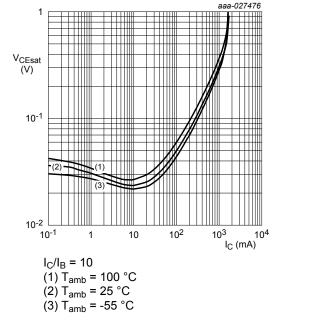


Fig. 9. Collector-emitter saturation voltage as a function of collector current; typical values

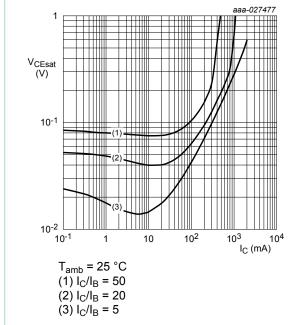


Fig. 10. Collector-emitter saturation voltage as a function of collector current; typical values

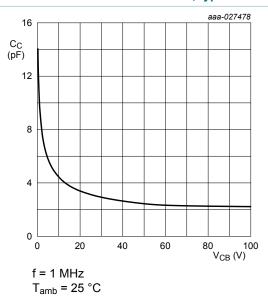


Fig. 11. Collector capacitance as a function of collector-base voltage; typical values

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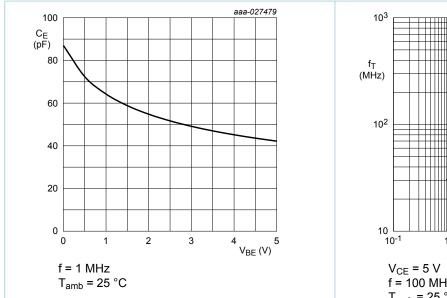


Fig. 12. Emitter capacitance as a function of emitterbase voltage; typical values

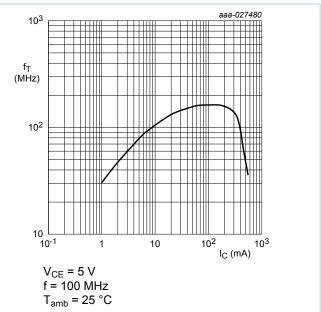


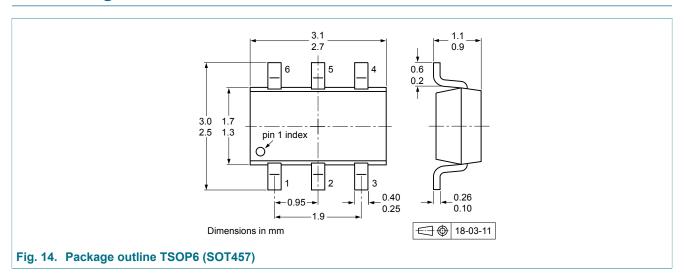
Fig. 13. Transition frequency as a function of collector current; typical values

## 11. Test information

### **Quality information**

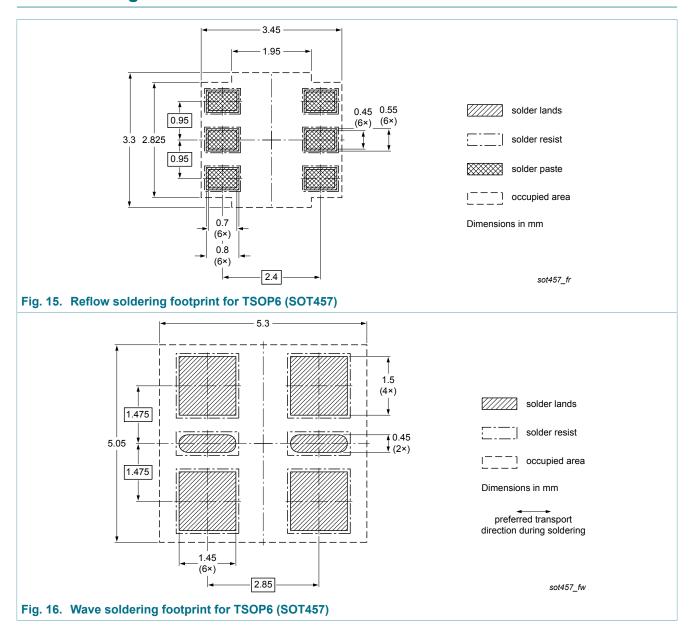
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

## 12. Package outline



### 80 V, 1 A NPN/NPN matched double transistors

## 13. Soldering



## 80 V, 1 A NPN/NPN matched double transistors

# 14. Revision history

### **Table 8. Revision history**

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
BCM56DS v.1	20180410	Product data sheet	-	-

#### 80 V, 1 A NPN/NPN matched double transistors

# 15. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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BCM56DS

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